

# RBV2500D - RBV2510D      SILICON BRIDGE RECTIFIERS

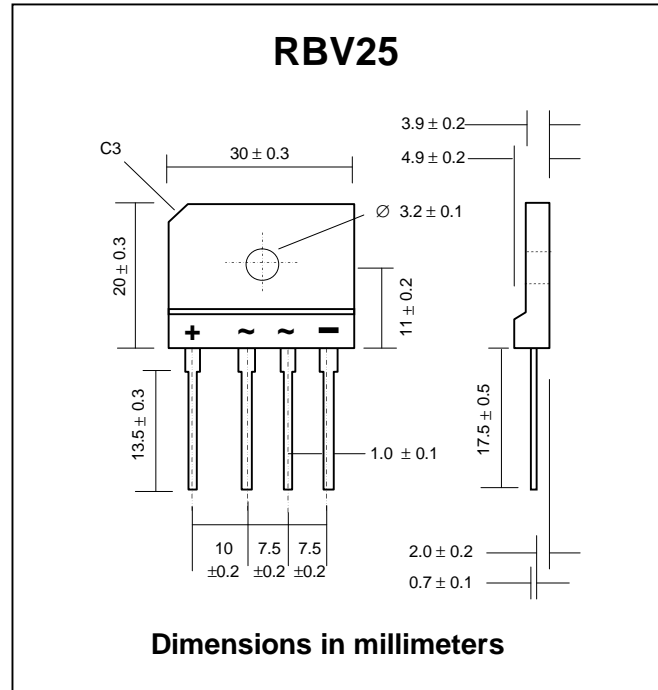
**PRV : 50 - 1000 Volts**  
**Io : 25 Amperes**

**FEATURES :**

- \* High current capability
- \* High surge current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* High case dielectric strength of 2000 V<sub>dc</sub>
- \* Ideal for printed circuit board
- \* Very good heat dissipation
- \* **Pb / RoHS Free**

**MECHANICAL DATA :**

- \* Case : Reliable low cost construction utilizing molded plastic technique
- \* Epoxy : UL94V-O rate flame retardant
- \* Terminals : Plated lead solderable per MIL-STD-202, Method 208 guaranteed
- \* Polarity : Polarity symbols marked on case
- \* Mounting position : Any
- \* Weight : 8.17 grams ( Approximaly )



**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

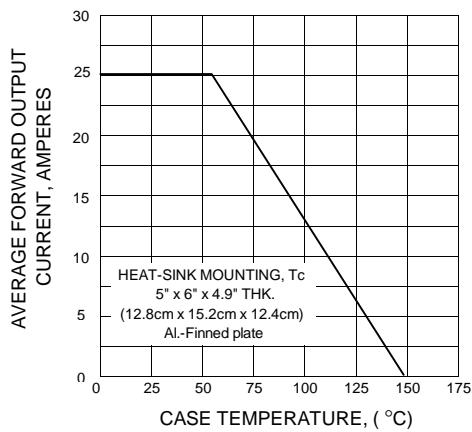
RATING	SYMBOL	RBV 2500D	RBV 2501D	RBV 2502D	RBV 2504D	RBV 2506D	RBV 2508D	RBV 2510D	UNIT	
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V	
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V	
Maximum Average Forward Current T <sub>c</sub> = 55°C	I <sub>F(AV)</sub>	25								A
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	400								A
Current Squared Time at t < 8.3 ms.	I <sup>2</sup> <sub>t</sub>	375								A <sup>2</sup> S
Maximum Forward Voltage per Diode at I <sub>F</sub> = 25 A	V <sub>F</sub>	1.1								V
Maximum DC Reverse Current      T <sub>a</sub> = 25 °C at Rated DC Blocking Voltage      T <sub>a</sub> = 100 °C	I <sub>R</sub>	10								µA
	I <sub>R(H)</sub>	200								µA
Typical Thermal Resistance (Note 1)	R <sub>θJC</sub>	1.2								°C/W
Operating Junction Temperature Range	T <sub>J</sub>	- 40 to + 150								°C
Storage Temperature Range	T <sub>STG</sub>	- 40 to + 150								°C

**Notes :**

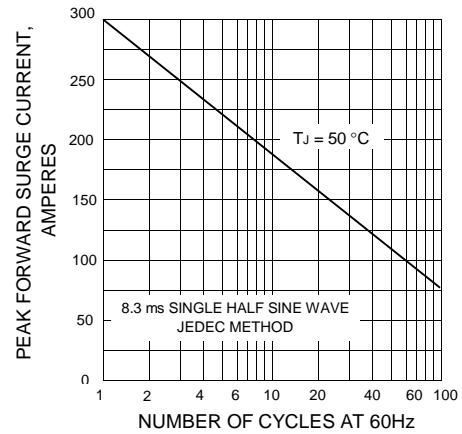
1. Thermal Resistance from junction to case with units mounted on a 5" x 6" x 4.9" (12.8cm.x 15.2cm.x 12.4cm.) Al.-Finned Plate

### RATING AND CHARACTERISTIC CURVES ( RBV2500D - RBV2510D )

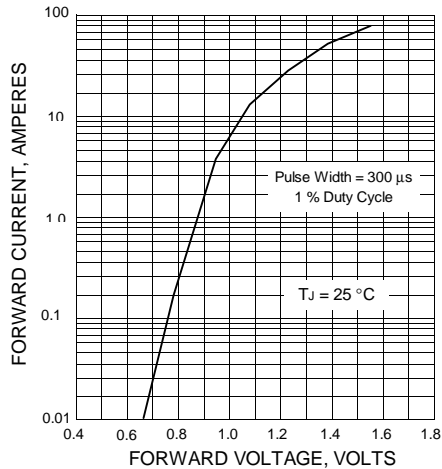
**FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



**FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.3 - TYPICAL FORWARD CHARACTERISTICS PER DIODE**



**FIG.4 - TYPICAL REVERSE CHARACTERISTICS PER DIODE**

